

4V Drive Pch MOS FET

RSR015P03

●Structure

Silicon P-channel MOS FET

●Features

- 1) Low On-resistance
- 2) Space saving—small surface mount package (TSMT3)
- 3) 4V drive

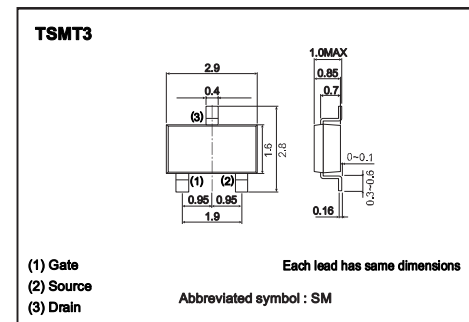
●Applications

Switching

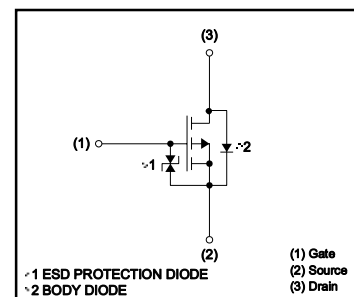
●Packaging specifications

Type	Package	Taping
	Code	TL
	Basic ordering unit (pieces)	3000
RSR015P03		○

■External dimensions (Unit : mm)



●Inner circuit



●Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		V_{DS}	-30	V
Gate-source voltage		V_{GS}	±20	V
Drain current	Continuous	I_D	±1.5	A
	Pulsed	I_{DP} ¹	±6	A
Source current (Body diode)	Continuous	I_S	-0.5	A
	Pulsed	I_{SP} ¹	-6	A
Total power dissipation		P_D ²	1	W
Channel temperature		T_{ch}	150	°C
Range of storage temperature		T_{stg}	-55 to +150	°C

¹ $P_W \leq 10 \mu s$, Duty cycle $\leq 1\%$ ² Mounted on a ceramic board

●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	$R_{th(ch-a)}$ ¹	125	°C/W

¹ Mounted on a ceramic board

Transistors

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	–	–	±10	μA	$V_{GS}=±20V$, $V_{DS}=0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	–30	–	–	V	$I_D = -1mA$, $V_{GS}=0V$
Zero gate voltage drain current	I_{DSS}	–	–	–1	μA	$V_{DS} = -30V$, $V_{GS}=0V$
Gate threshold voltage	$V_{GS(th)}$	–1.0	–	–2.5	V	$V_{DS} = -10V$, $I_D = -1mA$
Static drain-source on-state resistance	$R_{DS(on)}$	–	170	235	mΩ	$I_D = -1.5A$, $V_{GS} = -10V$
		–	270	375	mΩ	$I_D = -0.8A$, $V_{GS} = -4.5V$
		–	320	440	mΩ	$I_D = -0.8A$, $V_{GS} = -4V$
Forward transfer admittance	$ Y_{fs} $	0.9	–	–	S	$V_{DS} = -10V$, $I_D = -0.8A$
Input capacitance	C_{iss}	–	190	–	pF	$V_{DS} = -10V$
Output capacitance	C_{oss}	–	45	–	pF	$V_{GS}=0V$
Reverse transfer capacitance	C_{rss}	–	30	–	pF	$f=1MHz$
Turn-on delay time	$t_{d(on)}$	–	6	–	ns	$V_{DD} = -15V$ $I_D = -0.8A$
Rise time	t_r	–	8	–	ns	$V_{GS} = -10V$
Turn-off delay time	$t_{d(off)}$	–	22	–	ns	$R_L=19Ω$
Fall time	t_f	–	6	–	ns	$R_G=10Ω$
Total gate charge	Q_g	–	2.6	–	nC	$V_{DD} = -15V$ $V_{GS} = -5V$
Gate-source charge	Q_{gs}	–	1.0	–	nC	$I_D = -1.5A$
Gate-drain charge	Q_{gd}	–	0.7	–	nC	$R_L=10Ω$ $R_G=10Ω$

Pulsed

●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_{SD}	–	–	–1.2	V	$I_S = -0.5A$, $V_{GS}=0V$

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